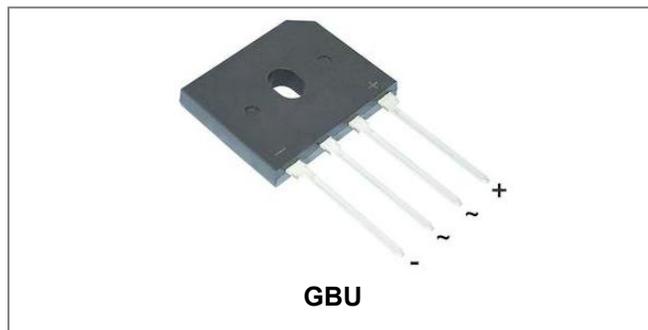


GBU8005G THRU GBU810G

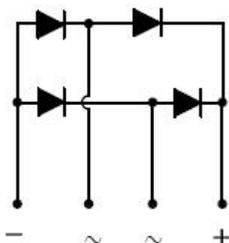
Single-Phase 8.0A Glass Passivated Bridge Rectifier



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: GBU, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

Maximum Ratings: @ $T_A=25^{\circ}\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	GBU 8005G	GBU 801G	GBU 802G	GBU 804G	GBU 806G	GBU 808G	GBU 810G	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average forward rectified output current (Note 1) @ $T_C = 90^{\circ}\text{C}$	I_o	8.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	200							A

Electrical Characteristics: @T_A=25°C unless otherwise specified

Type Number	Symbol	GBU 8005G	GBU 801G	GBU 802G	GBU 804G	GBU 806G	GBU 808G	GBU 810G	Units
Forward Voltage (per element) @I _F =4A @I _F =8A	V _F				1.0 1.1				V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _{RM}				5.0 500				μA
I ² t Rating for fusing (t <8.3ms)	I ² t				166				A ² s
Typical Junction Capacitance(per leg) (Note 2)	C _J				70				pF

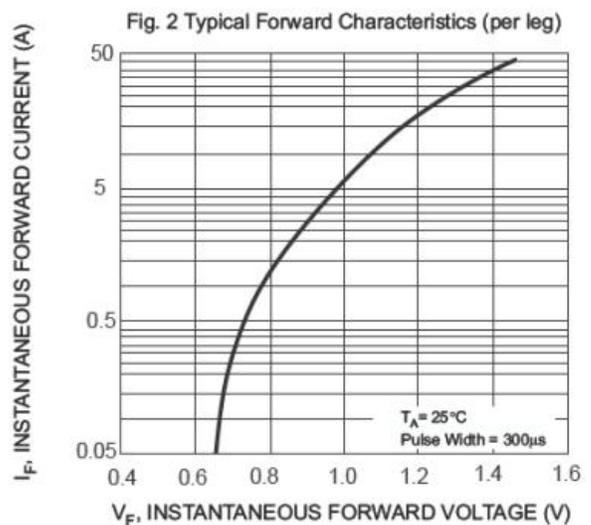
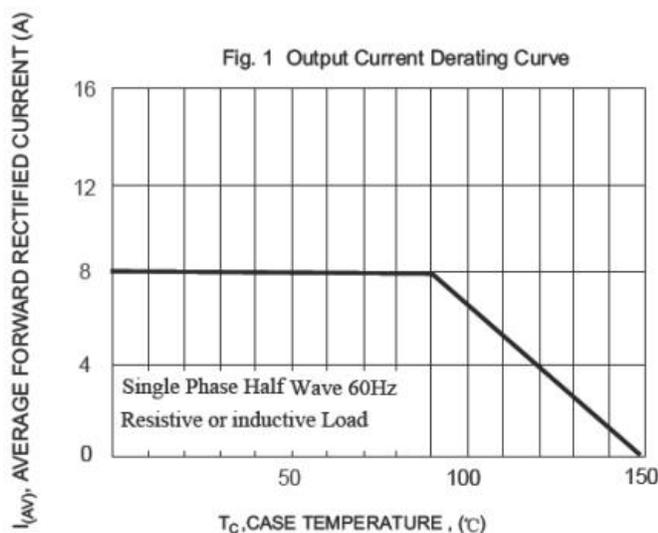
* Pulse width < 300 μs, duty cycle < 2%

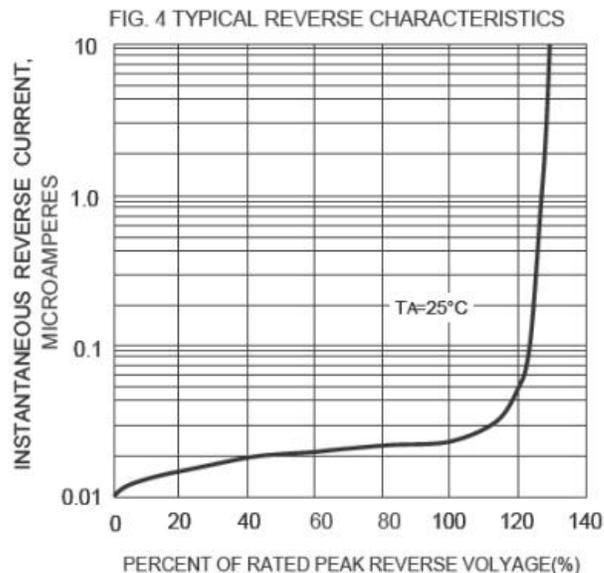
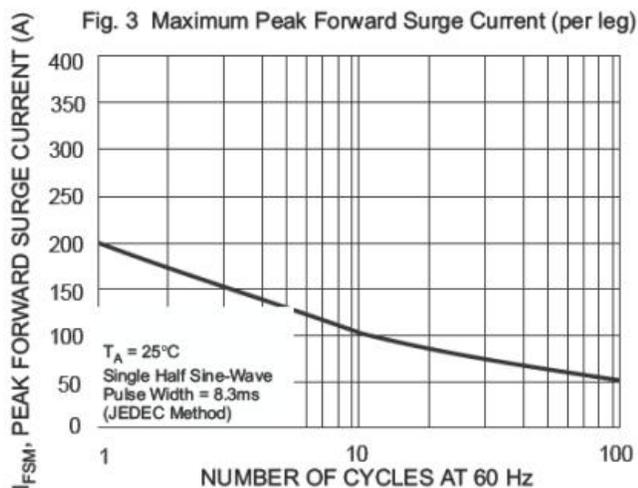
Thermal-Mechanical Specifications: @T_A=25°C unless otherwise specified

Type Number	Symbol	GBU 8005G	GBU 801G	GBU 802G	GBU 804G	GBU 806G	GBU 808G	GBU 810G	Units
Typical Thermal Resistance (per leg) (Note 3)	R _{θJA} R _{θJL}				30.9 7.3				°C/W
Operating and Storage Temperature Range	T _J , T _{STG}				-55 to +150				°C

Note: 1. Mounted on glass epoxy PC board with 1.3mm² solder pad.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
3. Device mounted on 50mm x 50mm x 1.6mm Cu Plate Heat sink.

Ratings and Characteristics Curves



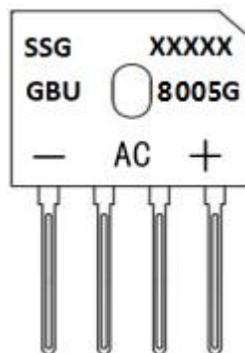


Ordering Information

Device	Package	Plating	Shipping
GBU8005G THRU GBU810G	GBU(Pb-Free)	Pure Sn	20pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

SSG = SSG
YY = Year
WW = Week
L = Lot Number
GBU8005G = Type Number

Cautions: Molding resin
Epoxy resin UL:94V-0

**Technical Data
Data Sheet N1919, Rev. A**



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